

## APPLICATIONS OF DIRECT VOLTAMMETRY IN THE STUDY OF HIGH TEMPERATURE SUPRACONDUCTOR / REDOX ELECTROLYTE INTERFACE

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**ABSTRACT.** A new method based on direct voltammetry was used to study the variation of current density with temperature at the high temperature superconductor/redox electrolyte interface (in the proximity of critical temperature).

For this purpose, we have solved the Volterra integral equation with known  $K(t,u)$  kernel and  $f(t)$  function, thus allowing the  $j(t)$  current density estimation.

From  $j(\eta)$  vs.  $\eta$  an explanation for the reversible solution form to a Butler-Volmer irreversible solution form trespassing in the case of critical temperature involvement, is suggested.

### INTRODUCTION

In nonaqueous media direct voltammetry of  $\text{Pb} \mid \text{Bi}_2 \text{Sr}_2 \text{CaCu}_2 \text{O}_x$  (2212) phase is similar in appearance to that of noble metals [1].

Reasonable results can be obtained, despite the distortion induced by ohmic drop, in a nonstationary method.

A specific expression of Volterra equation is considered for an inert electrodic material [2].

By solving this equation we found the current density  $j(t)$  in reversible and irreversible reactions cases (cathodic branch).

Until now there were not reported results about  $T_c$  estimation using nonstationary methods from classical point of view.

### RESULTS AND DISCUSSIONS

In the Fredholm alternative [3] a Volterra integral equation is:

$$j_F(t) = \lambda \frac{j^0 N^*(t)}{\pi^{1/2}} \int_0^t \frac{j_F(u)}{(t-u)^{1/2}} du + f(t) \quad (1)$$

where

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$$N^*(t) = \frac{\exp(-\beta fvt)}{F\sqrt{D_0 c_0}} + \frac{\exp[(1-\beta)fvt]}{F\sqrt{D_R c_R}}; \quad f(t) = j^0 \left\{ \exp(-\beta fvt) - \exp[(1-\beta)fvt] \right\} \quad \lambda=-1 \quad (1')$$

D - diffusion coefficient; c - concentration,  $f = F/RT$ ; T - temperature; t - time;  $|v|$  is the overpotential ( $\eta$ ) and  $v < 0$ .

If  $D_0 = D_R = D$  and  $c_0 = c_R = c$ , by neglecting capacitive current,  $j_F(t)$  is the measured current density in closed circuit conditions.

In this case (1') is:

$$N^*(t) = \bar{N} \exp(\beta f|v|t) [1 + \exp(-f|v|t)]; \quad f(t) = j^0 \exp(\beta f|v|t) [1 - \exp(-f|v|t)] \quad (1'')$$

$$\bar{N} = \frac{1}{F\sqrt{Dc}}; \quad f = \frac{F}{RT}$$

We can write integral eq. solution in serial form:

$$j(t) = j_0(t) + \lambda j_1(t) + \dots + \lambda^k j_k(t) + \dots \quad (2)$$

where:

$$j_0(t) = f(t) = j^0 \exp(\beta f|v|t) [1 - \exp(-f|v|t)] \quad (2')$$

$$j_{k+1}(t) = \frac{j^0 N^*(t)}{\pi^{1/2}} \int_0^t \frac{j_k(u)}{(t-u)^{1/2}} du \quad (2'')$$

and for  $j_1(t)$  result:

$$j_1(t) = \frac{j^0 N^*(t)}{\pi^{1/2}} \int_0^t j^0 \exp(\beta f|v|u) [1 - \exp(-f|v|u)] (t-u)^{-1/2} du \quad (3)$$

In proximity of t,  $(t-u)^{-1/2} \rightarrow \infty$  and:  $\exp(\beta f|v|u) [1 - \exp(-f|v|u)] \rightarrow \exp[\beta f|v|t] [1 - \exp(-f|v|t)]$ .

It was possible to be applied an average theorem for eq.(3), and we found:

$$\int_0^t j^0 \exp(\beta f|v|u) [1 - \exp(-f|v|u)] (t-u)^{-1/2} du \cong j^0 \exp(\beta f|v|t) [1 - \exp(-f|v|t)] \cdot \quad (4)$$

$$\cdot \int_0^t (t-u)^{-1/2} du \cong j^0 \exp(\beta f|v|t) [1 - \exp(-f|v|t)] 2\sqrt{t}$$

with

$$\int_0^t (u-0)^m (t-u)^n du = (t-0)^{m+n+1} \frac{\Gamma(m+1)\Gamma(n+1)}{\Gamma(m+n+2)} \quad (5)$$

( $t>0$ ;  $m>-1$ ;  $n>-1$ )

where  $\Gamma(\ )$  function is:

$$\Gamma(n) = \int_0^{\infty} u^{n-1} \exp(-u) du ; n \neq 0, -1, -2, -3, \dots \quad (6)$$

$$\Gamma(n+1) = n\Gamma(n) ; \Gamma(1) = 1 ; \Gamma(1/2) = \pi^{1/2}$$

Using (4) and (5):

$$j_1(t) = [j^0 N^*(t)] j^0 \exp(\beta f |v| t) [1 - \exp(-f |v| t)] \frac{1}{\Gamma(1/2 + 1)} t^{1/2} \quad (7)$$

The little error occuring by averaging procedure from (4), failed, because odd therms in serial form (2) appear with (-) and even therms appear with (+).

Generally:

$$j_k(t) = [j^0 N^*(t)]^k j^0 \exp(\beta f |v| t) [1 - \exp(-f |v| t)] \frac{t^{k/2}}{\Gamma(k/2 + 1)} \quad (8)$$

By using (2") in the same averaging conditions we obtained:

$$j_{k+1}(t) = [j^0 N^*(t)]^{k+1} j^0 \exp(\beta f |v| t) [1 - \exp(-f |v| t)] \frac{t^{(k+1)/2}}{\Gamma[(k+1)/2 + 1]} \quad (8')$$

and (8) is indeed a general expression.

Finally the current density is:

$$j(t) = j^0 \exp(\beta f |v| t) [1 - \exp(-f |v| t)] \left\{ 1 + \left\{ \lambda j^0 \bar{N} \exp(\beta f |v| t) [1 + \exp(-f |v| t)] \right\} \cdot \frac{t^{1/2}}{\Gamma(1/2 + 1)} + \dots + \left\{ \lambda j^0 \bar{N} \exp(\beta f |v| t) [1 + \exp(-f |v| t)] \right\}^k \frac{t^{k/2}}{\Gamma(k/2 + 1)} + \dots \right\} \quad (9)$$

A (9) serie is convergente and deriving this expression, after few algebric operation finaly results [3]

$$\frac{1}{(\lambda j^0 \bar{N})^2} \left[ \frac{dj(t)}{dt} - \frac{\beta + (1 - \beta) \exp(-f |v| t)}{1 - \exp(-f |v| t)} f |v| j(t) \right] = \left\{ 1 + 2 \left[ \beta - \frac{\exp(-f |v| t)}{1 + \exp(-f |v| t)} \right] \cdot f |v| t \right\} \exp(2\beta f |v| t) [1 + \exp(-f |v| t)]^2 j(t) + \left\{ 1 + 2 \left[ \beta - \frac{\exp(-f |v| t)}{1 + \exp(-f |v| t)} \right] f |v| t \right\} \cdot \exp(2\beta f |v| t) [1 - \exp(-2f |v| t)] \frac{1}{\lambda \bar{N} \pi^{1/2} t^{1/2}} \quad (10)$$

This is an ordinary diferential equation of first order for direct voltammetry.

a) *current density for reversible redox reactions.*

In this case  $j^0 \rightarrow \infty$  and from (10) (with  $\lambda = -1$ ) we have:

$$j(t) = \frac{1 - \exp(-f|v|t)}{1 + \exp(-f|v|t)} \frac{F\sqrt{D}c}{\pi^{1/2}t^{1/2}} \quad (11)$$

Equation (11) can be written

$$j(\eta) = \frac{F\sqrt{D}c v^{1/2}}{\pi^{1/2}} \cdot \text{th} \left( \frac{f\eta}{2} \right) \frac{1}{\eta^{1/2}} \quad (12)$$

(using overpotential  $\eta$ )

b) *current density for irreversible redox reactions.*

With  $j^0 \rightarrow 0$ , from eq. (10)

$$\frac{dj(t)}{dt} = \left[ \beta + \frac{\exp(-f|v|t)}{1 - \exp(-f|v|t)} \right] f|v|j(t) \quad (13)$$

and by integration:

$$j(t) = j^0 \exp(\beta|v|t) [1 - \exp(-f|v|t)] \quad (14)$$

$$\text{or } j(\eta) = j^0 \exp(\beta\eta) [1 - \exp(-f\eta)] \quad (14')$$

By deriving the eq. (12) is obtained:

$$4f\eta \exp(-f\eta) - 1 + \exp(-2f\eta) = 0 \quad (15)$$

$$\text{or: } \text{sh}(f\eta) = 2f\eta \quad (15')$$

and after numerical computation a maximum at:

$$\eta_p = 2,18 \cdot RT/F \quad (16)$$

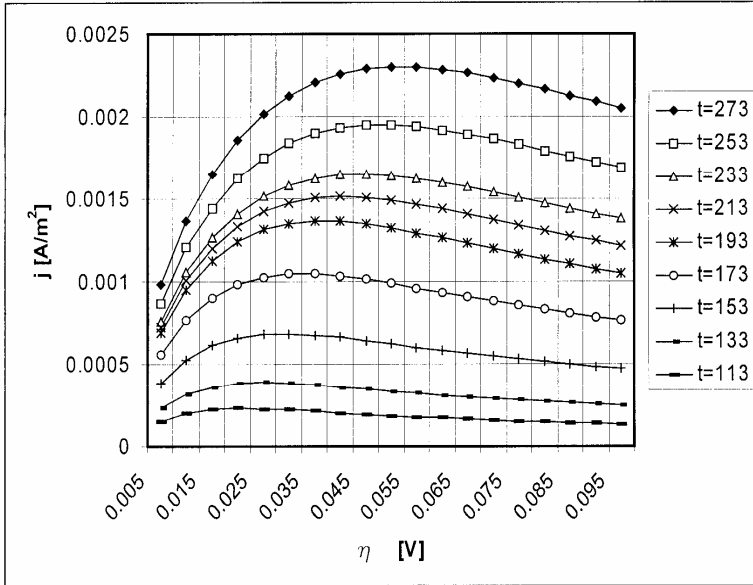
dependent of the temperature.

Let's consider the diffusion coefficient at different temperatures of: 2 mM  $\text{Cp}_2^* \text{Fe}$  in 0,2 M  $\text{Bu}_4\text{NPF}_6$ , 1/2 (PrCN/EtCl) solvent mixture [4].

Numerical computations was applied to eq.(12). This procedure generated nonlinear  $j$  vs.  $\eta$  plots for 50 mV/s scan rate (see fig.1) at low temperature conditions.

Initially at 273 K  $j$  vs.  $\eta$  is a reversible shape, but finally at about 100 K appears change. By decreasing the temperature both value  $j(\eta)$  and  $\eta_{\text{peak}}$  change.

$\eta_{\text{peak}} \rightarrow \eta_{\text{Tc}}$  (for critical temperature), and the reversible current density  $j(\eta)$  should became a Butler -Volmer irreversible type.



**Fig.1.**  $j$  vs.  $\eta$  plots ( 50 mV/s scan rate ) in different temperature conditions between 113 K and 273 K

In critical conditions ( $T_c$ ) the numerical estimation show that one can write:

$$FD^{1/2}c|v|^{1/2} \cdot \pi^{1/2} = j^0 \exp(\beta\eta_{Tc}) [1 + \exp(-f\eta_{Tc})] \cdot \eta_{Tc}^{1/2}$$

From this eq. it is possible to calculate the critical temperature in classical treatment.

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